onse '

Ω @ $V_{GS} = 15 V$

- Ultra Low Gate Charge ($Q_{G(tot)} = 283 \text{ nC}$)
- Low Effective Output Capacitance (Coss = 424 pF)
- 100% Avalanche Tested
- AEC-Q101 Qualified and PPAP Capable
- This Device is Halide Free and RoHS Compliant with exemption 7a, Pb–Free 2LI (on second level interconnection)

Typical Applications

• Automotive On Board Charger

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NVBG015N065SC1

NVBG015N065SC1

NVBG015N065SC1

TYPICAL CHARACTERISTICS (continued)

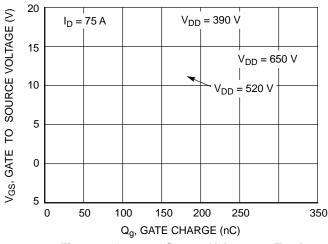


Figure 7. Gate-to-Source Voltage vs. Total Charge

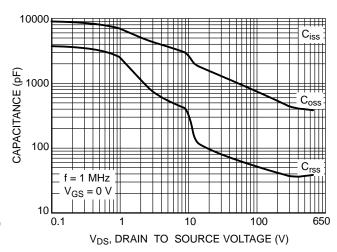


Figure 8. Capacitance vs. Drain-to-Source Voltage

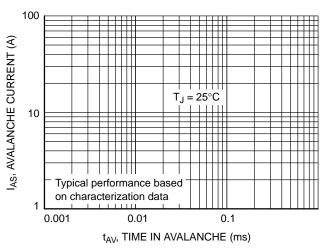


Figure 9. Unclamped Inductive Switching Capability

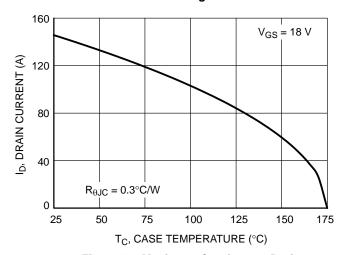


Figure 10. Maximum Continuous Drain Current vs. Case Temperature

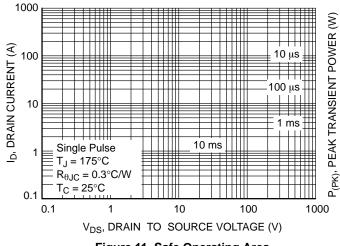


Figure 11. Safe Operating Area

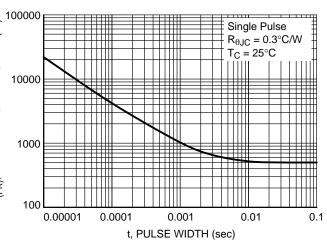


Figure 12. Single Pulse Maximum Power Dissipation

D²PAK7 (TO-263-7L HV) CASE 418BJ ISSUE B

DATE 16 AUG 2019

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GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

